

Afisarea articolelor -19-0(6) pentru cuvântul-cheie "Film growth"

Hot wall beam epitaxial growth of PbTe layers on BaF₂/CaF₂/Si(111) substrates

Belenciuc Alexandr

Institute of Applied Physics, Academy of Sciences of Moldova

Proceedings of the International Semiconductor Conference

Vol. 1. 2000. New Jersey. [DOI 10.1109/SMICND.2000](https://doi.org/10.1109/SMICND.2000).

Disponibil online 29 November, 2023. Descarcări-0. Vizualizări-164

Synthesis and characterization of functional nanostructured zinc oxide thin films

Șișianu Sergiu¹, Chow Lee², Lupan Oleg¹, Șișianu Teodor¹

¹ Technical University of Moldova,

ECS Transactions

Vol. 3, Ediția 9. 2006. Pennington, New Jersey. [ISBN 1566775094, 1566775094, 978-156677509-0](https://doi.org/10.1109/1566775094_1566775094_978-156677509-0).

Disponibil online 12 February, 2024. Descarcări-0. Vizualizări-98

Growth and characterization of crack-free GaN films grown on cracked Si-doped GaN templates

Sia Engkee¹, Hao Maosheng¹, Chua Soo Jin¹, Tighineanu Ion^{2,3}, Ichizli V.⁴, Mutamba Kabula⁴, Hartnagel Hans Ludwig⁴, Zhang Ji⁵, Tripathy Sudhiranjan R.⁵

¹ Institute of Materials Research Engineering, Singapore ,

² Institute of Applied Physics, Academy of Sciences of Moldova,

³ Technical University of Moldova,

⁵ National University of Singapore

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/ 2001 / ISSN 0277-786X /ISSNe 1996-756X

Disponibil online 14 February, 2024. Descarcări-1. Vizualizări-78

About the edge luminescence of cadmium sulphide thin layers grown on molybdenum

Raevschi Simion, Gorceac Leonid, Coval Andrei, Chetruș Petru

Moldova State University

Proceedings of the International Semiconductor Conference

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Disponibil online 8 December, 2023. Descarcări-0. Vizualizări-161

Epitaxial relations in BaF₂ films grown by MBE on Si(111) substrates

Belenciuc Alexandr, Fedorov Alexander, Zencenco V., Lukash V., Vasilyev A.

Institute of Applied Physics, Academy of Sciences of Moldova

Proceedings of the International Semiconductor Conference

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Disponibil online 8 December, 2023. Descarcări-0. Vizualizări-89

Raman scattering analysis of InGaAs/InP: Effect of rare earth (Dysprosium) addition during liquid phase epitaxial growth

Tighineanu Ion, Ursachi Veaceslav, Podor Balint, Csontos L., Şontea Victor

Academy of Sciences of Moldova

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Disponibil online 25 January, 2024. Descarcări-0. Vizualizări-95



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Actualizat: 26.06.2024, accesat: 26.06.2024
Disponibil: <https://ibn.idsi.md>

